

GP10A - GP10M

AXIAL LEADED SILICON RECTIFIER DIODES

VOLTAGE RANGE: 50-1000V

CURRENT: 1.0 A

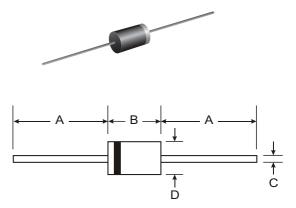
Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case:D O 4 1 , Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.35 grams (approx.)
- Mounting Position: Any
- Marking: Type Number





| DO-41 | | | | | | | | |
|----------------------|-------|-------|--|--|--|--|--|--|
| Dim | Min | Мах | | | | | | |
| Α | 25.40 | — | | | | | | |
| В | 4.06 | 5.21 | | | | | | |
| С | 0.71 | 0.864 | | | | | | |
| D | 2.00 | 2.72 | | | | | | |
| All Dimensions in mm | | | | | | | | |

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

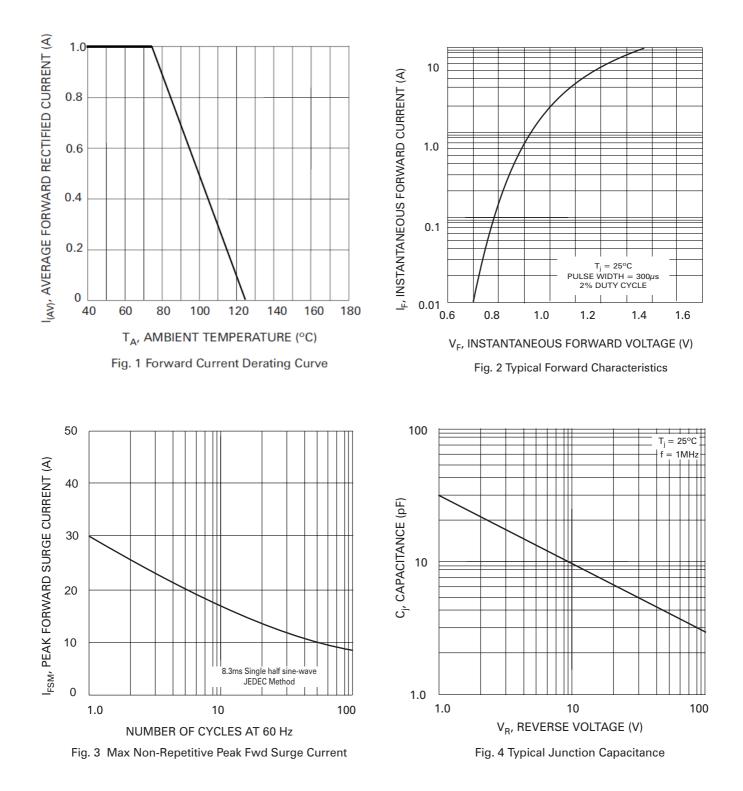
| Characteristic | Symbol | GP10A | GP10B | GP10D | GP10G | GP10J | GP10K | GP10M | Unit |
|---|--------------------|-------------|-------|-------|-------|-------|-------|-------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | Vrrm Vrwm Vr | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V |
| RMS Reverse Voltage | VR(RMS) | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V |
| Average Rectified Output Current (Note 1) $@T_A = 75^{\circ}C$ | lo | 1.0 | | | | | | A | |
| Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method) | Ifsm | 30 | | | | | | А | |
| Forward Voltage $@I_F = 1.0A$ | Vfм | 1.0 | | | | | | V | |
| Peak Reverse Current $@T_A = 25^{\circ}C$ At Rated DC Blocking Voltage $@T_A = 100^{\circ}C$ | Iгм | 5.0 50 | | | | | | μA | |
| Typical Junction Capacitance (Note 2) | Cj | 15 | | | | | | pF | |
| Typical Thermal Resistance Junction to Ambient (Note 1) | R <i>θ</i> JA | | | | 50 | | | | K/W |
| Operating Temperature Range | Tj | -65 to +125 | | | | | | °C | |
| Storage Temperature Range | Tstg | -65 to +150 | | | | | | °C | |

*Glass passivated forms are available upon request

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.





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